

描述

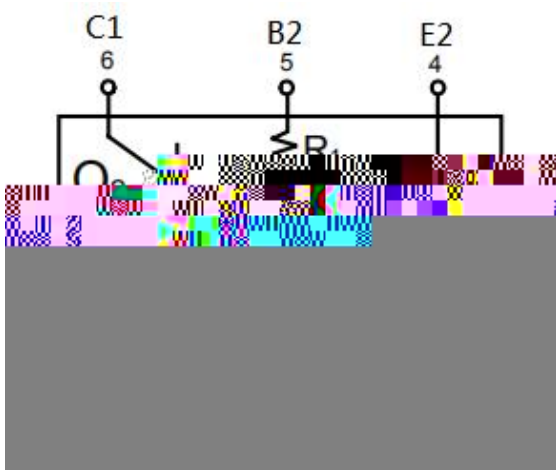
silicon NPN and PNP transistor in a SOT-363 Plastic Package

特征

With built-in bias resistors, simplify circuit design, reduce a quantity of parts and manufacturing process, HF Product.

用途

Switching applications, interface circuit and driver circuit applications.



放大及印章代码

Marking	H335
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Parameter	Symbol	Rating	Unit
Supply Voltage	V_{CC}	50	V
Input Voltage	V_{IN}	12	V
		-5	V
Output Current	I_O	100	mA
Collector Dissipation	P_C	187	mW
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55~150	

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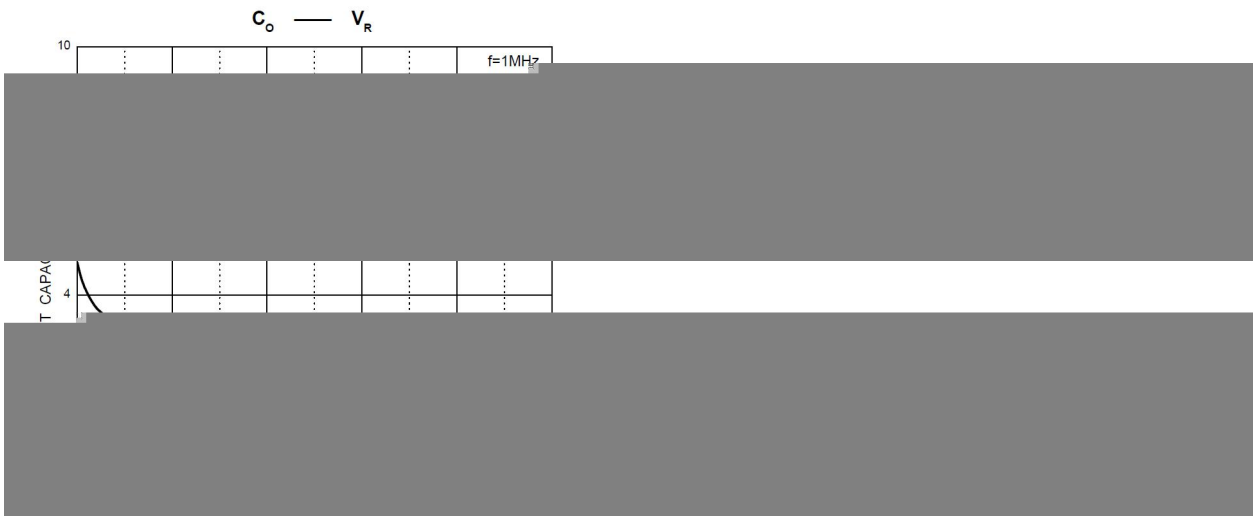
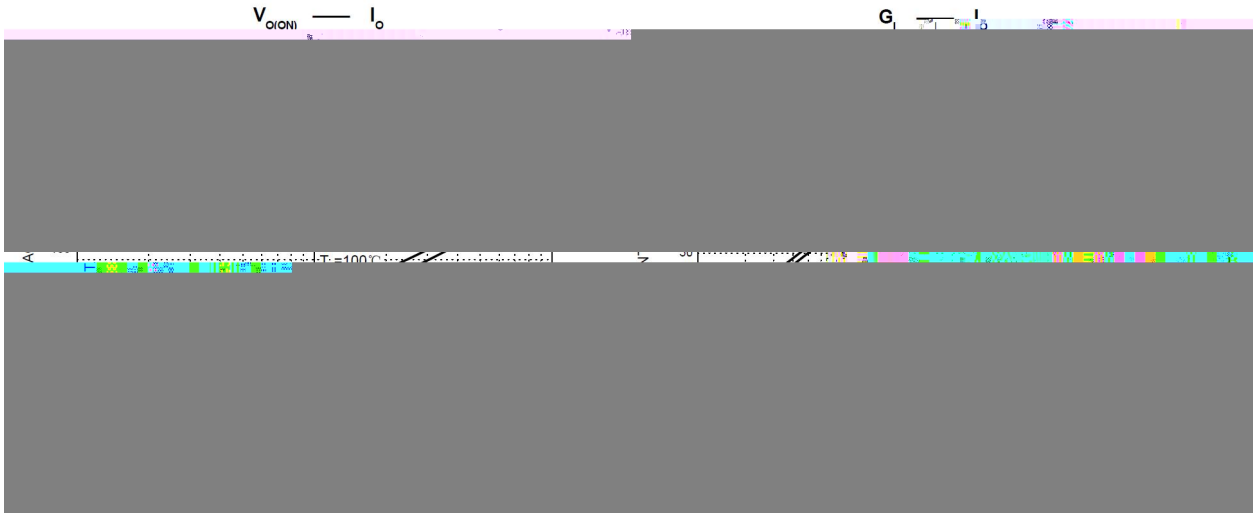
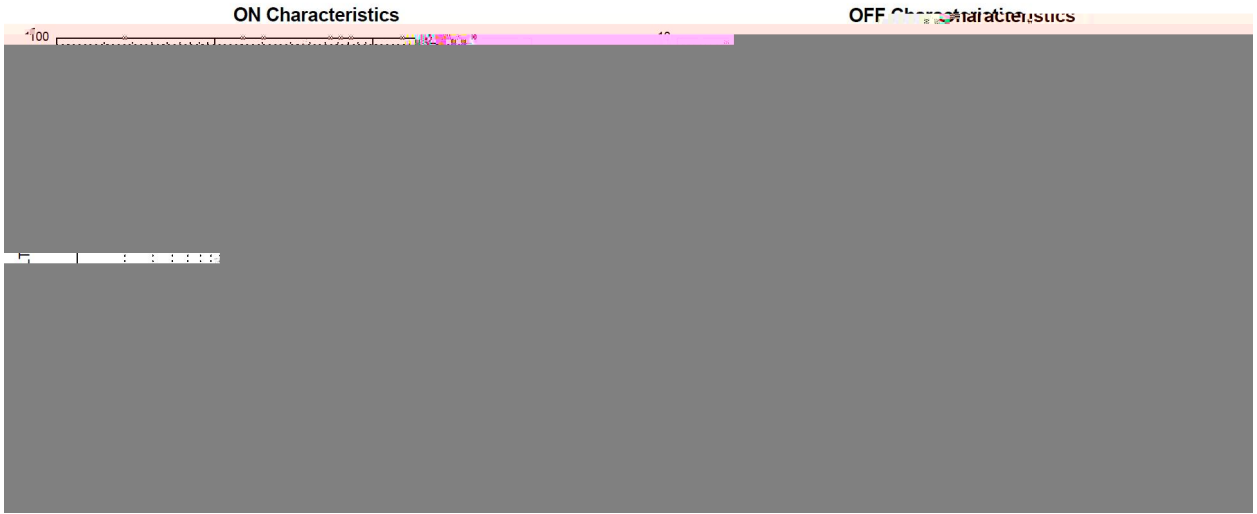
Parameter Symbol

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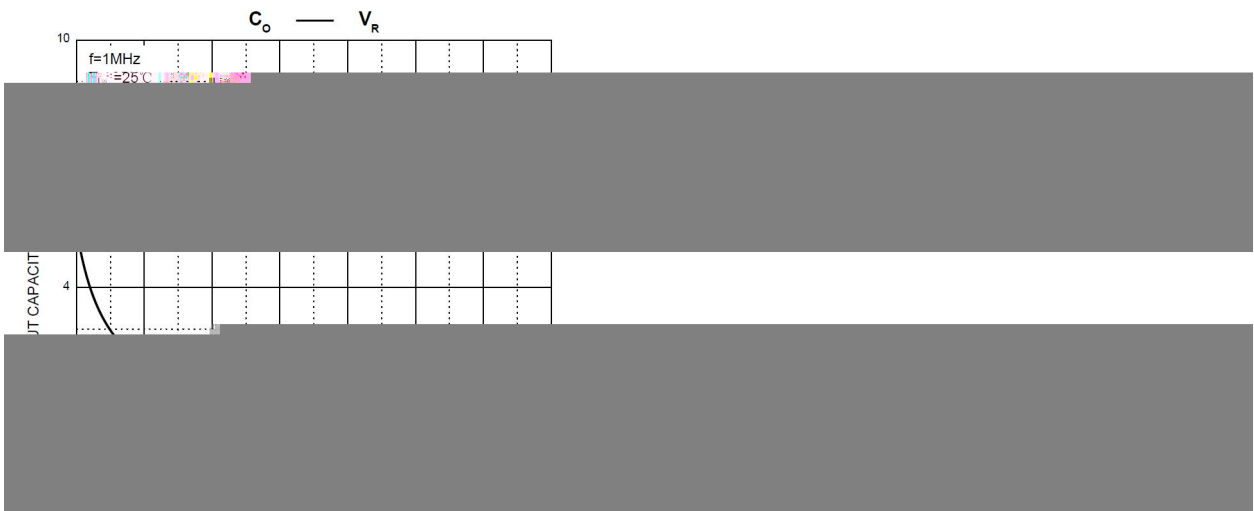
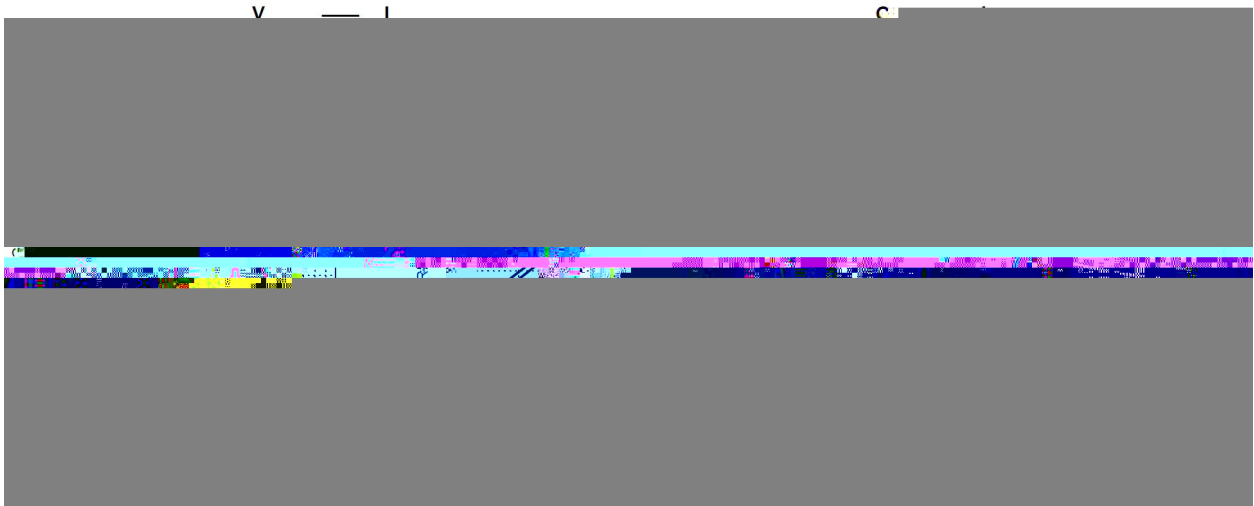
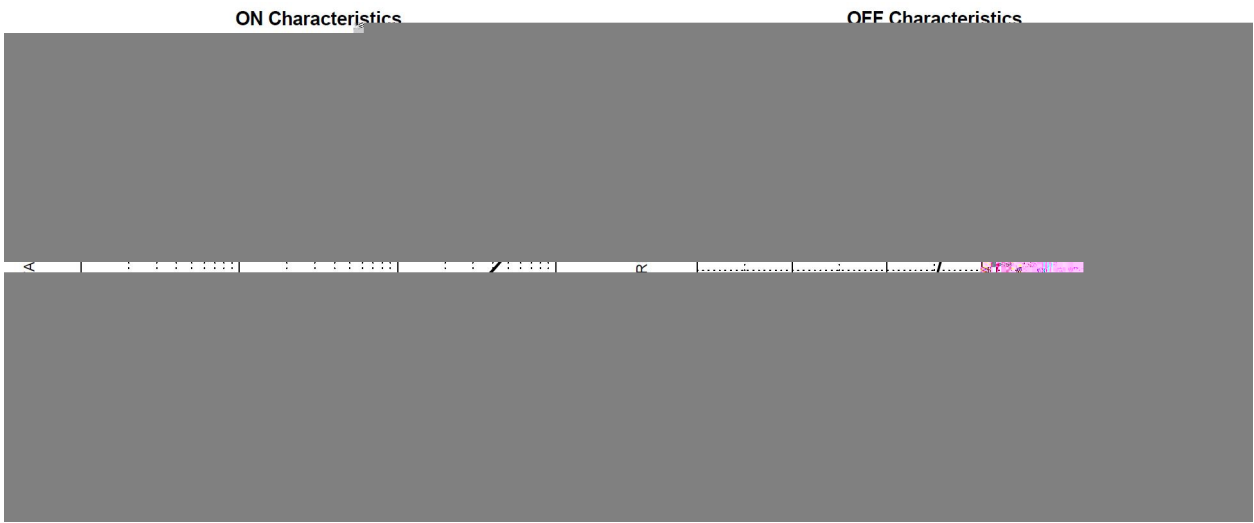
Parameter	Symbol	Rating	Unit
Supply Voltage	V_{CC}	-50	V
Input Voltage	V_{IN}	-12	V
		5	V
	I_o	-100	mA

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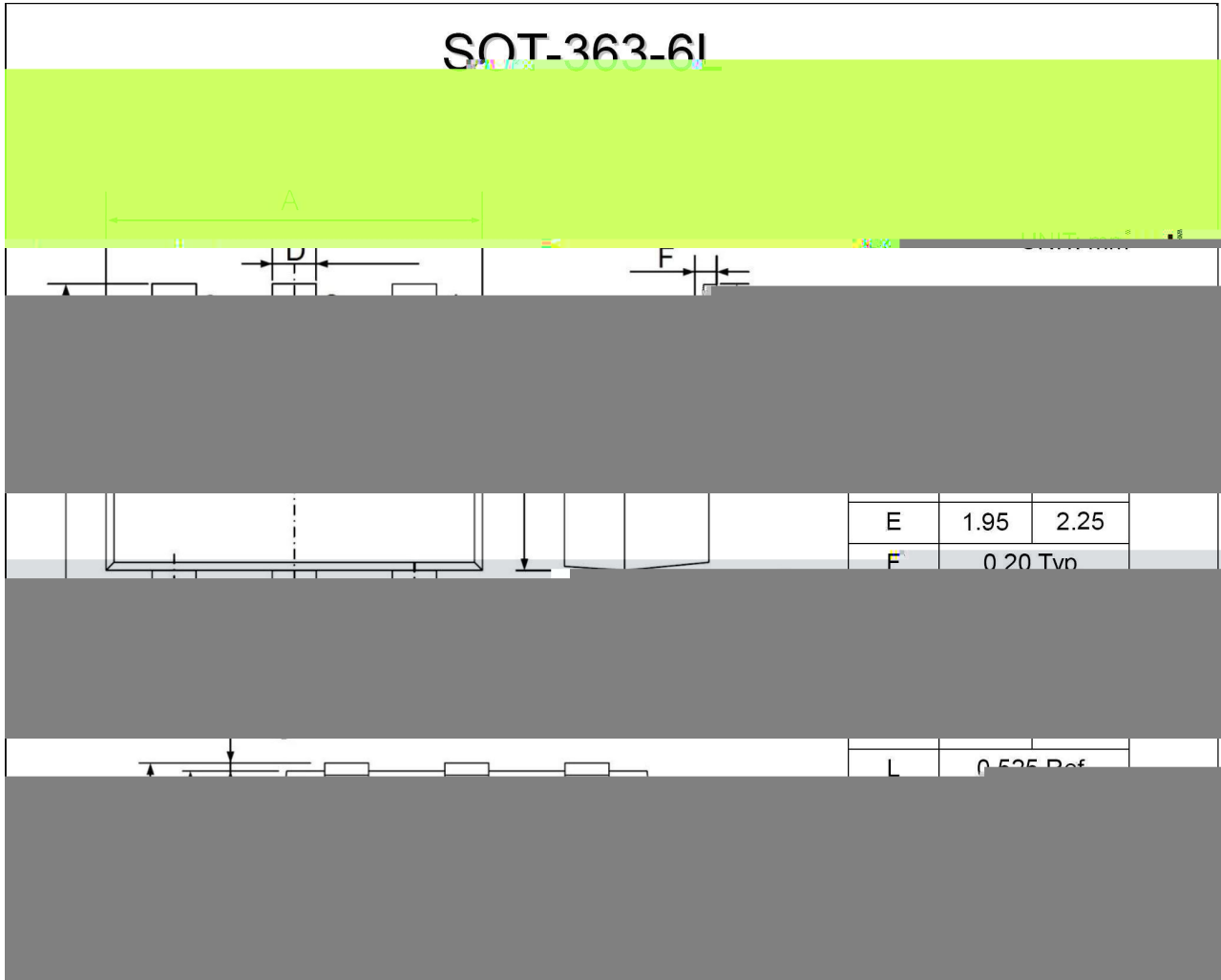
电参数曲线图



电参数曲线图



外形尺寸图 (506" = 3%)



回流焊温度曲线图-无铅 (Pb-Free) Temperature Profile for Reflow Soldering (Pb-Free)



90s

1 150 180 60 90sec;
2 245 5 5 0.5sec;

Note:

1. Preheating: 150~180 , Time: 60~90sec.

2. Peak